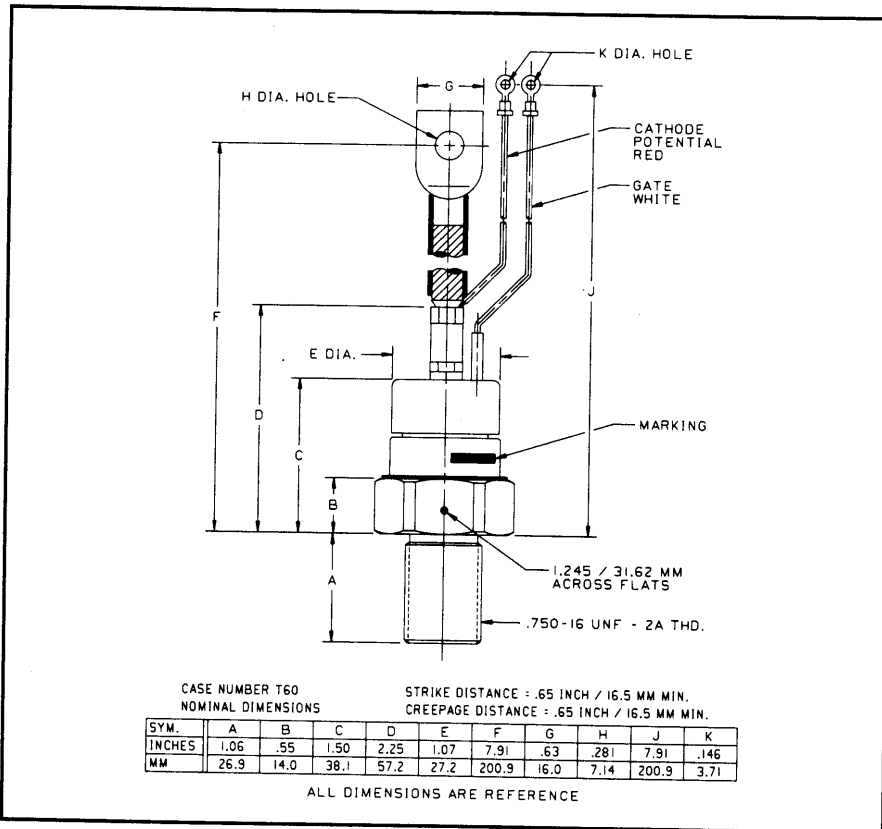
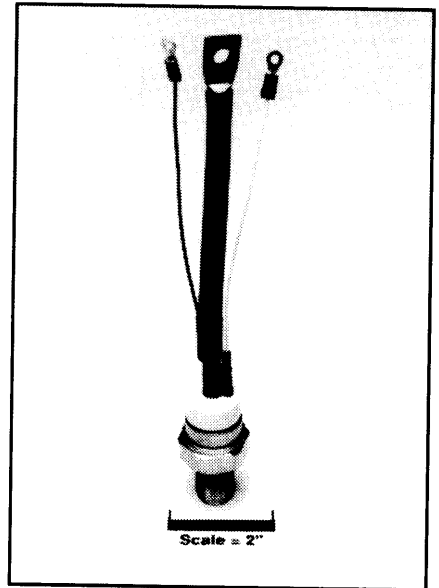


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 Powerex, Europe, S.A. 428 Avenue G. Durand, BP107, 72003 Le Mans, France (43) 41.14.14

Phase Control SCR
 150 Amperes Average
 1600 Volts



C180 (Outline Drawing)



C180 Phase Control SCR
 150 Amperes Average, 1600 Volts

Ordering Information:

Select the complete five or six digit part number you desire from the table, i.e. C180PM is a 1600 Volt, 150 Ampere Phase Control SCR.

Type	Voltage		Current
	V_{DRM}	V_{RRM} Code	$I_T(av)$
C180	200	B	150
	400	D	
	600	M	
	800	N	
	1000	P	
	1200	PB	
	1400	PD	
1600	PM		

Description:

Powerex Silicon Controlled Rectifiers (SCR) are designed for phase control applications. These are all-diffused, compression bonded encapsulated (CBE) devices employing the field-proven amplifying (di/namic) gate.

Features:

- Low On-State Voltage
- High di/dt
- High dv/dt
- Hermetic Packaging
- Excellent Surge and I^2t Ratings

Applications:

- Power Supplies
- Battery Chargers
- Motor Control



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C180
Phase Control SCR
 150 Amperes Average, 1600 Volts

Absolute Maximum Ratings

	Symbol	C180	Units
RMS On-State Current @ $T_C = 90^\circ\text{C}$	$I_{T(RMS)}$	235	Amperes
Average On-State Current @ $T_C = 90^\circ\text{C}$	$I_{T(av)}$	150	Amperes
Peak One-Cycle Surge (Non Repetitive) On-State Current (60Hz)	I_{TSM}	3500	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}	3200	Amperes
Critical Rate-of-Rise of On-State Current (Non-Repetitive)	di/dt	800	Amperes/ μs
Critical Rate-of-Rise of On-State Current (Repetitive)	di/dt	150	Amperes/ μs
I^2t (for Fusing), 8.3 milliseconds	I^2t	50,800	A^2sec
Peak Gate Power Dissipation	P_{GM}	10	Watts
Average Gate Power Dissipation	$P_{G(av)}$	2	Watts
Storage Temperature	T_{STG}	-40 to 150	$^\circ\text{C}$
Operating Temperature	T_J	-40 to 125	$^\circ\text{C}$
Mounting Torque		250 to 300	in.-lb.
Mounting Torque		28 to 34	N-M

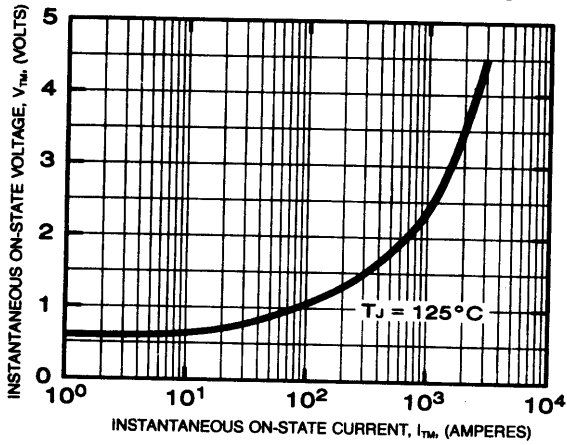
Electrical and Thermal Characteristics

Characteristics	Symbol	Test Conditions	C180	Units
Voltage—Blocking State Maximums				
Forward Leakage, Peak	I_{DRM}	$T_J = 125^\circ\text{C}; V_{DRM} = \text{Rated}$	20	mA
Reverse Leakage, Peak	I_{RRM}	$T_J = 125^\circ\text{C}; V_{RRM} = \text{Rated}$	20	mA
Current—Conducting State Maximums				
Peak On-State Voltage	V_{TM}	$T_J = 25^\circ\text{C}, I_{TM} = 1500\text{A}$	2.85	Volts
Switching				
Typical Turn-Off Time	t_q	$I_T = 150\text{A}, T_J = 125^\circ\text{C}, di_R/dt = 12.5\text{A}/\mu\text{sec}$ Reapplied $dv/dt = 20\text{V}/\mu\text{sec}$, Linear to $0.8V_{DRM}$, $V_R = 50\text{V}$	100	μsec
Typical Delay Time	t_d	$I_T = 100\text{A}, V_{DRM} = \text{Rated}$ Gate Supply = 10V Open Ckt, 25 Ω , 0.1 μsec Rise Time	1.0	μsec
Min. Critical dv/dt exponential to V_{DRM}	dv/dt	$T_J = 125^\circ\text{C}$, Gate Open	200	$\text{V}/\mu\text{sec}$
Thermal				
Maximum Thermal Resistance Junction to Case	$R_{\theta JC}$		0.14	$^\circ\text{C}/\text{Watt}$
Case to Sink, Lubricated	$R_{\theta CS}$		0.075	$^\circ\text{C}/\text{Watt}$
Gate—Maximum Parameters				
Gate Current to Trigger	I_{GT}	$T_C = 25^\circ\text{C}; V_D = 6\text{Vdc}, R_L = 3\Omega$	150	mA
Gate Voltage to Trigger	V_{GT}	$T_C = -40^\circ\text{C}$ to $125^\circ\text{C}, V_D = 6\text{Vdc}, R_L = 3\Omega$	3.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_J = 125^\circ\text{C}$, Rated V_{DRM} , $R_L = 1000\Omega$	0.15	Volts
Peak Forward Gate Current	I_{GTM}		10	Amperes
Peak Reverse Gate Voltage	V_{GRM}		5	Volts

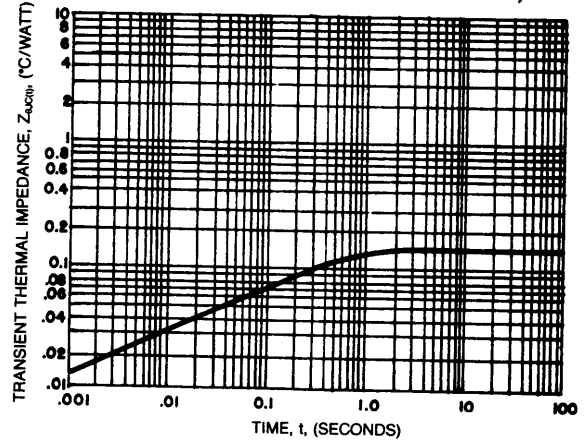
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C180
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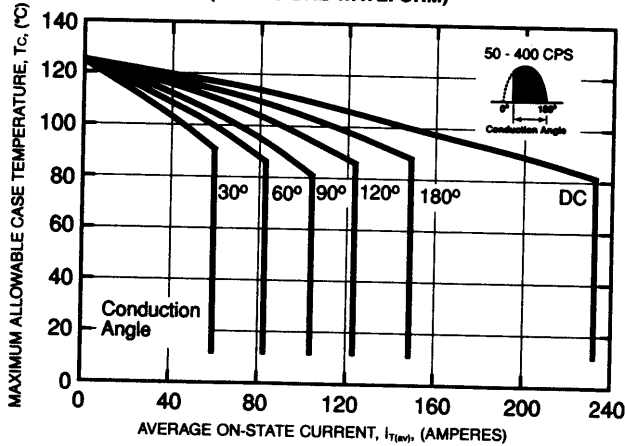
MAXIMUM ON-STATE CHARACTERISTICS



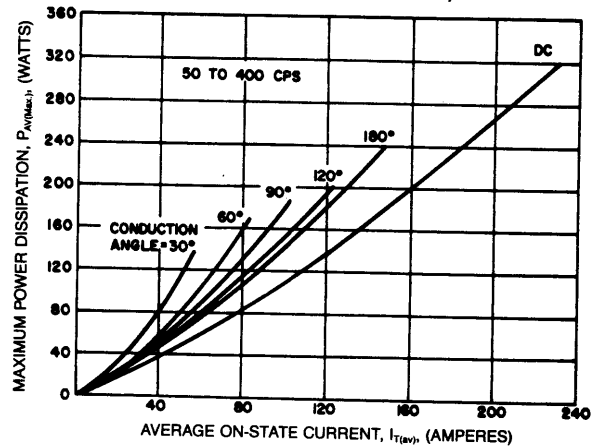
TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



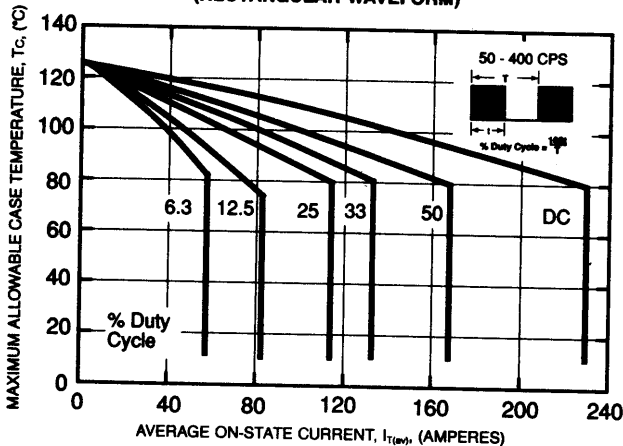
MAXIMUM ALLOWABLE CASE TEMPERATURE (SINUSOIDAL WAVEFORM)



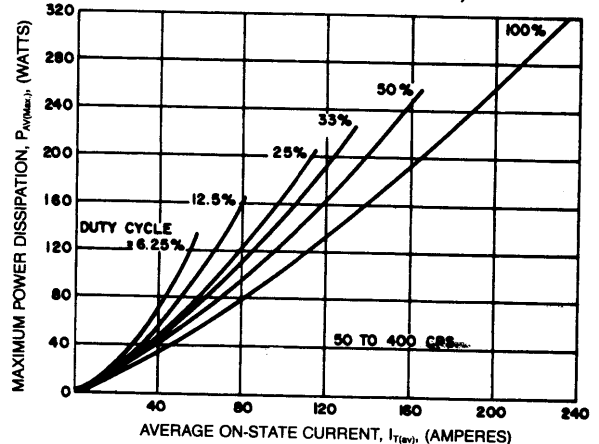
MAXIMUM ON-STATE POWER DISSIPATION (SINUSOIDAL WAVEFORM)



MAXIMUM ALLOWABLE CASE TEMPERATURE (RECTANGULAR WAVEFORM)

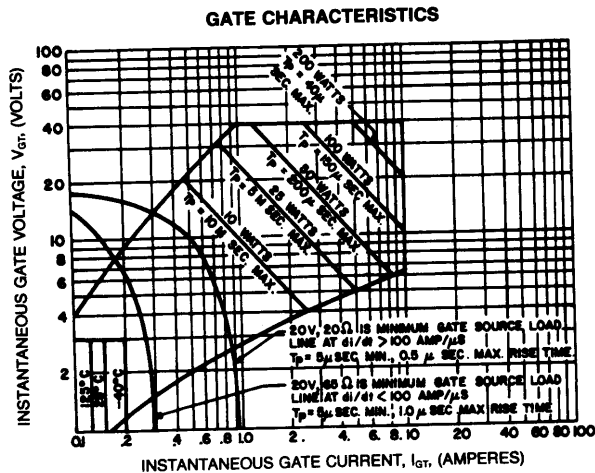
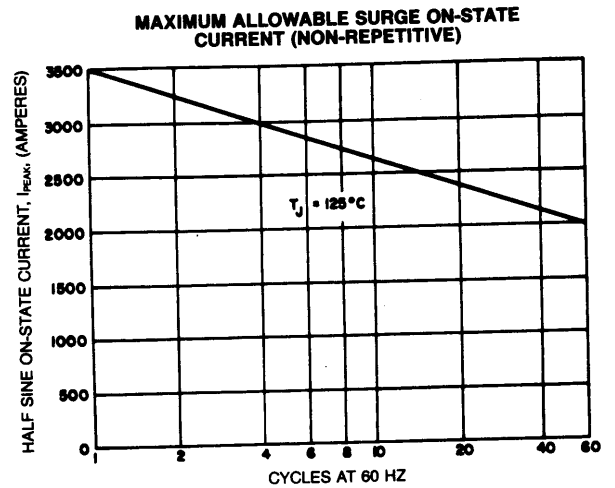
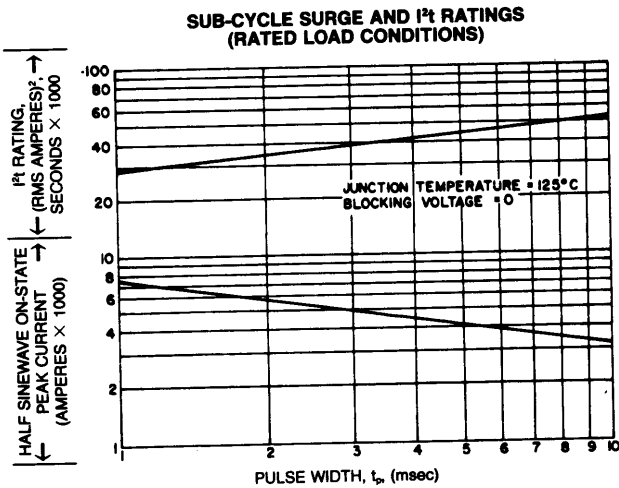
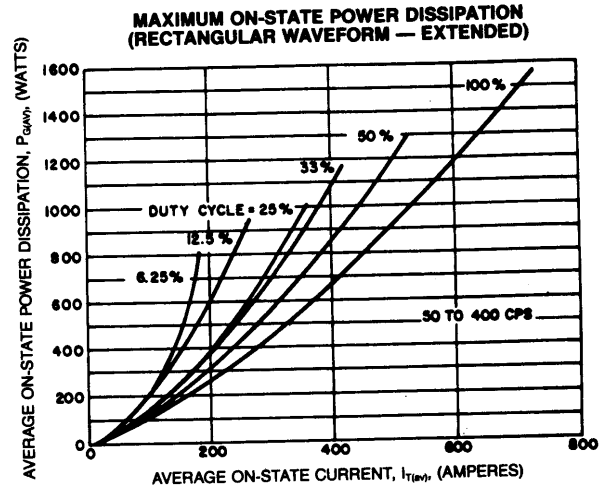
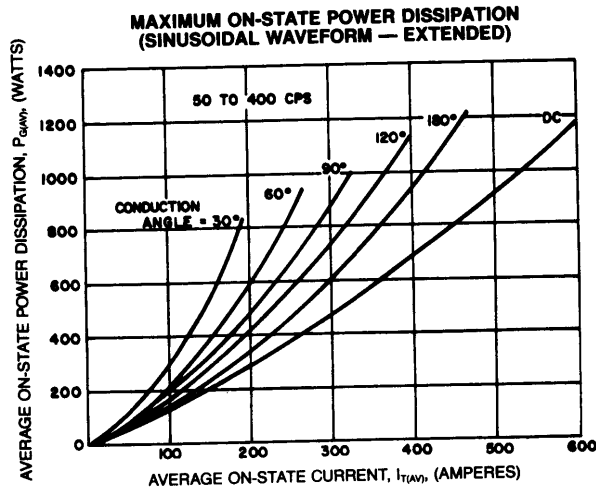


MAXIMUM ON-STATE POWER DISSIPATION (RECTANGULAR WAVEFORM)



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C180
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NOTES:

- Maximum allowable average gate dissipation = 5 watts.
- The locus of possible dc trigger points lie outside the boundaries shown at various case temperatures.
- t_p = Rectangular gate current pulse width (5 μs min. duration; 1.0 μs max. rise time for 20V, 65 Ω source).
- 20V - 20 Ω is the minimum gate source load line when rate of circuit current rise > 100 Amp/ μs or anode rate of current rise > 200 Amps/ μs ($t_p = 5\mu\text{s}$ min., 0.5 μs max. rise time).

Maximum long-term repetitive anode $di/dt = 500 \text{ Amps}/\mu\text{s}$ with 20V - 20 Ω gate source.